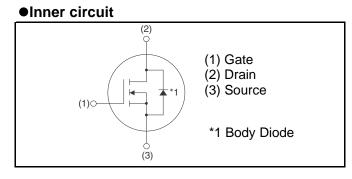


V _{DSS}	1200
R _{DS(on)} (Typ.)	$80 \text{m}\Omega$
I _D	40A ^{*1}

Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive



Application

- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

• Absolute maximum ratings $(T_a = 25^{\circ}C)$

Parameter		Symbol	Value	Unit
Drain - Source voltage		V _{DSS}	1200	V
Continuous drain current $T_c = 25^{\circ}C$		ا _D *1	40	А
Pulsed drain current		I _{D,pulse} *2	140	А
Gate - Source voltage (DC)		V _{GSS}	-6 to 22	V
Gate - Source surge voltage (t _{surge} < 300nsec)		V _{GSS_surge} *3	-10 to 26	V
Junction temperature		Τ _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

•Electrical characteristics ($T_a = 25^{\circ}C$)

Doromotor	Sumbol	Conditions	Values			Linit	
Parameter	Symbol Conditions –		Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	V _{GS} = 0V, I _D = 1mA	1200	-	-	V	
		$V_{DS} = 1200V, V_{GS} = 0V$					
Zero gate voltage drain current	I _{DSS}	T _j = 25°C	-	1	10	μA	
		T _j = 150°C	-	2	-		
Gate - Source leakage current	I_{GSS^+}	$V_{GS} = +22V, V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current	I _{GSS-}	$V_{GS} = -6V, V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	V _{GS (th)}	$V_{DS} = V_{GS}, I_D = 4.4 \text{mA}$	1.6	2.8	4.0	V	
Static drain - source on - state resistance		V _{GS} = 18V, I _D = 10A					
	R _{DS(on)} *4	T _j = 25°C	-	80	111	mΩ	
		T _j = 125°C	-	115	-		
Gate input resistance	R_G	f = 1MHz, open drain	-	9.0	-	Ω	



•Electrical characteristics ($T_a = 25^{\circ}C$)

Deremeter	Symbol	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	g _{fs} ^{*4}	$V_{DS} = 10V, I_{D} = 10A$	-	3.7	-	S
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	2070	-	
Output capacitance	C _{oss}	V _{DS} = 800V	-	80	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	20	-	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} = 0V V _{DS} = 0V to 800V	-	99	-	pF
Turn - on delay time	t _{d(on)} *4	$V_{DD} = 400V, I_{D} = 10A$	-	23	-	
Rise time	t _r *4	V _{GS} = 18V/0V	-	39	-	20
Turn - off delay time	t _{d(off)} *4	$R_L = 40\Omega$	-	79	-	ns
Fall time	t _f *4	$R_{G} = 0\Omega$	-	28	-	
Turn - on switching loss	E _{on} ^{*4}	$V_{DD} = 600V, I_D = 10A$ $V_{GS} = 18V/0V$	-	255	-	
Turn - off switching loss	E _{off} *4	$R_G = 0\Omega, L = 750 \mu$ *E _{on} includes diode reverse recovery	-	27	-	μJ

•Gate Charge characteristics ($T_a = 25^{\circ}C$)

Parameter	Symbol Conditions	Conditions	Values			1.1.0.14
		Min.	Тур.	Max.	Unit	
Total gate charge	Q_g^{*4}	V _{DD} = 400V	-	110	-	
Gate - Source charge	Q _{gs} ^{*4}	I _D = 10A	-	24	-	nC
Gate - Drain charge	Q_{gd}^{*4}	V _{GS} = 18V	-	38	-	
Gate plateau voltage	V _(plateau)	$V_{DD} = 400V, I_D = 10A$	-	9.7	-	V

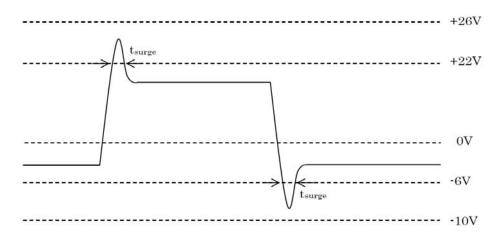
●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
Faranieler	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Inverse diode continuous, forward current	ا _S *1	T _c = 25°C	-	-	40	А	
Inverse diode direct current, pulsed	I _{SM} *2		-	-	140	А	
Forward voltage	V_{SD} *4	$V_{GS} = 0V, I_{S} = 10A$	-	4.7	-	V	
Reverse recovery time	t _{rr} *4	I _F = 10A, V _R = 600V di/dt = 650A/μs	-	51	-	ns	
Reverse recovery charge	Q _{rr} ^{*4}		-	194	-	nC	
Peak reverse recovery current	^{*4}		-	7.6	-	А	

*1 For T_j =175°C and thermal dissipation to ambience of 262W or more. Limited only by maximum temperature allowed.

*2 PW \leq 10µs, Duty cycle \leq 1%

*3 Example of acceptable Vgs waveform



*4 Pulsed

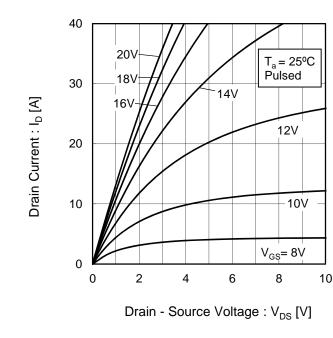
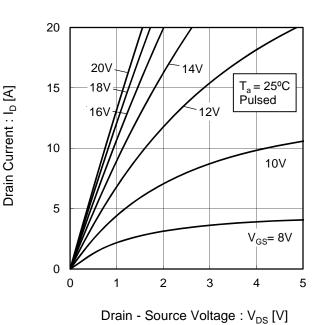
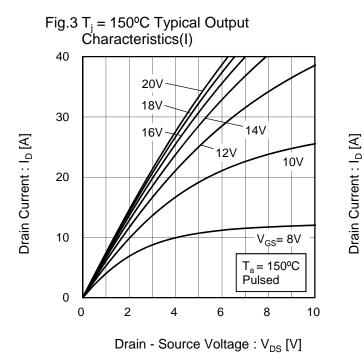
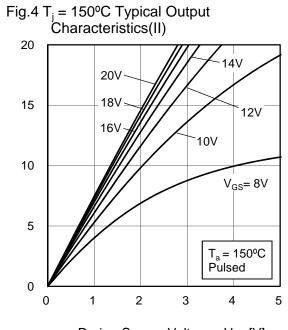


Fig.1 Typical Output Characteristics(I)

Fig.2 Typical Output Characteristics(II)







Drain - Source Voltage : V_{DS} [V]

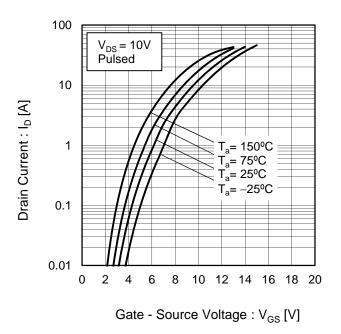


Fig.5 Typical Transfer Characteristics (I)

Fig.6 Typical Transfer Characteristics (II)

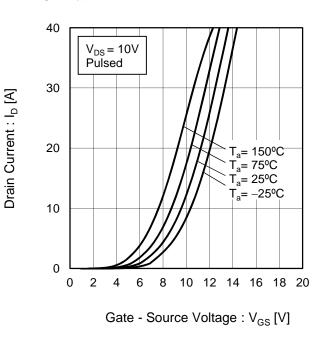
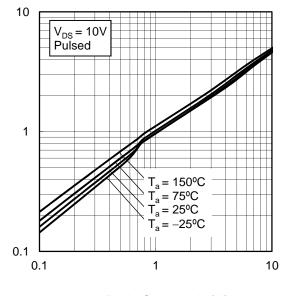


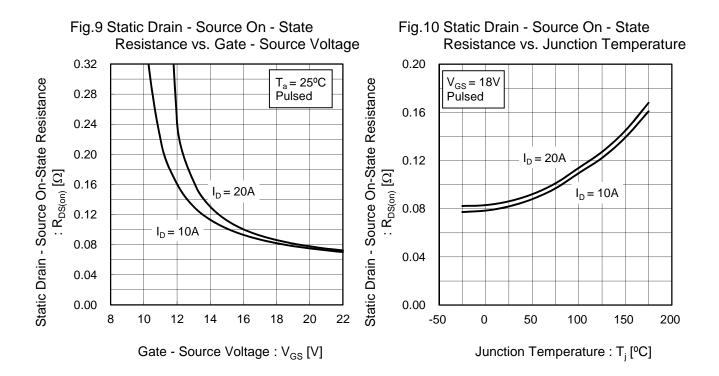
Fig.7 Gate Threshold Voltage vs. Junction Temperature 6 $V_{DS} = 10V$ $I_{D} = 4.4mA$ 5 Gate Threshold Voltage : V _{GS(th)} [V] 4 3 2 1 0 -50 0 50 100 150 200 Junction Temperature : T_i [°C]

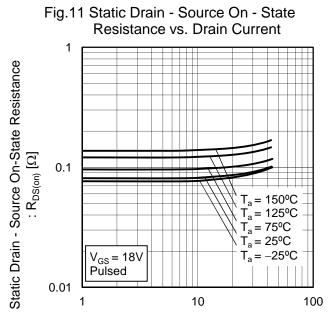
Fig.8 Transconductance vs. Drain Current

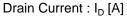


Drain Current : I_D [A]

Transconductance : g_{fs} [S]







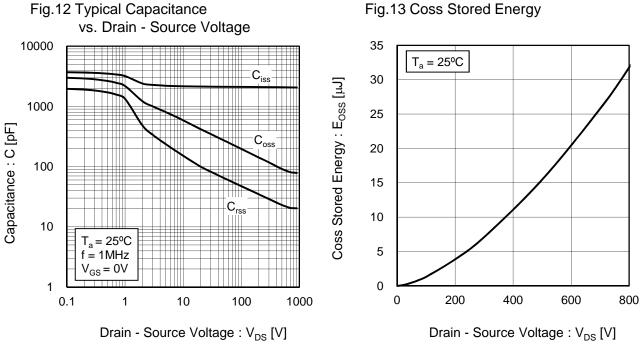
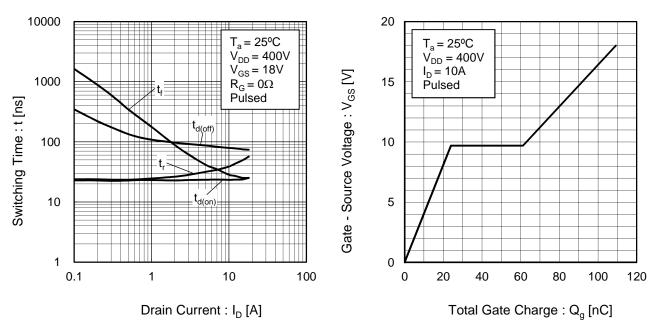
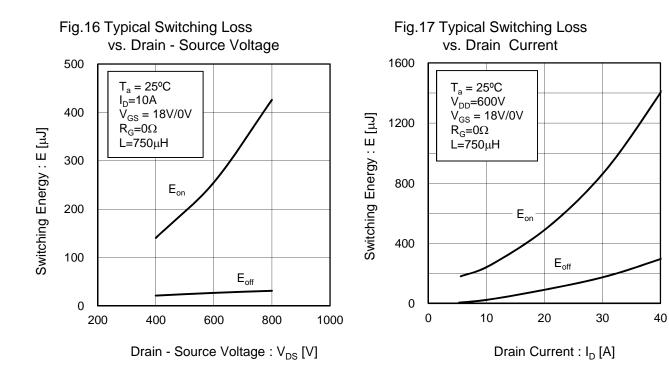
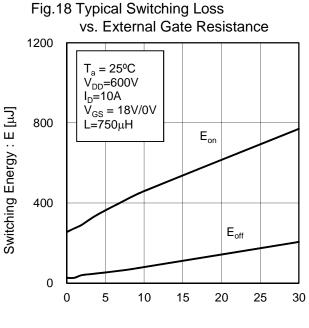


Fig.14 Switching Characteristics

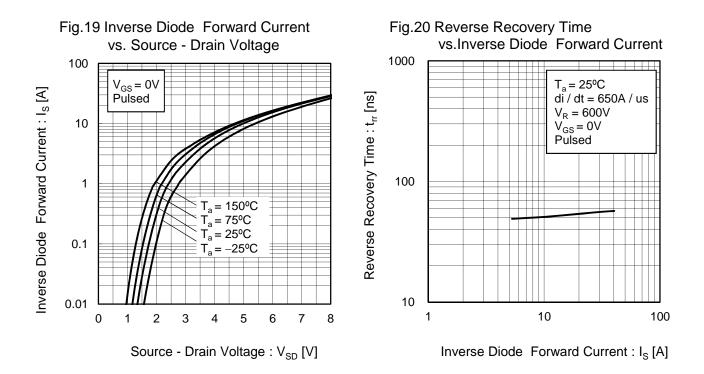




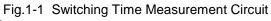




External Gate Resistance : $R_G [\Omega]$



Measurement circuits



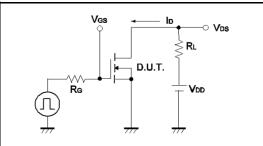


Fig.2-1 Gate Charge Measurement Circuit

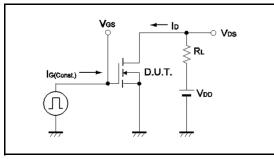


Fig.3-1 Switching Energy Measurement Circuit

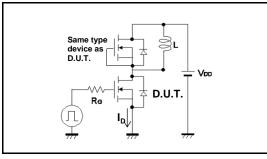
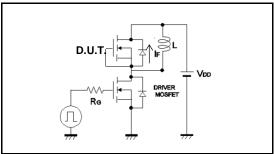
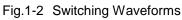


Fig.4-1 Reverse Recovery Time Measurement Circuit Fig.4-2 Reverse Recovery Waveform





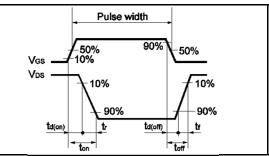


Fig.2-2 Gate Charge Waveform

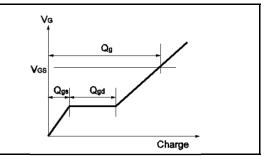
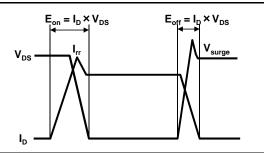
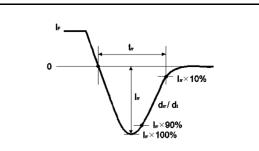


Fig.3-2 Switching Waveforms







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